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AUTOMOTIVE LOW-DROPOUT VOLTAGE REGULATORS

Check for Samples: TL750Mxx-Q1, TL751Mxx-Q1

FEATURES

- Qualified for Automotive Applications
- Low Dropout Voltage, Less Than 0.6 V at 750 mA
- Low Quiescent Current
- TTL- and CMOS-Compatible Enable on TL751M Series
- Load-Dump Protection
- Overvoltage Protection
- Internal Thermal Overload Protection
- Internal Overcurrent-Limiting Circuitry

DESCRIPTION

The TL750M and TL751M series are low-dropout positive voltage regulators specifically designed for automotive applications. The TL750M and TL751M series incorporate onboard overvoltage and current-limiting protection circuitry to protect the devices and the regulated system. Both series are fully protected against load-dump and reverse-battery conditions. Load-dump protection is up to a maximum of 60 V at the input of the device. Low quiescent current, even during full-load conditions, makes the TL750M and TL751M series ideal for use in applications that are permanently connected to the vehicle battery.

The TL750M and TL751M series offers 5-V, 8-V, and 12-V options. The TL751M series has the addition of an enable (ENABLE) input. The ENABLE input gives complete control over power up, allowing sequential power up or shutdown. When ENABLE is high, the regulator output is placed in the high-impedance state. The ENABLE input is TTL and CMOS compatible.

The TL750Mxx and TL751Mxx are characterized for operation over the virtual junction temperature range –40°C to 125°C.

AVAILABLE OPTIONS(1)

| TJ | V _O NOM (V) | PACKA | GE ⁽²⁾ | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|---------------------------|----------------|-------------------|-----------------------|------------------|
| | 5 V | TO-263-3 – KTT | Reel of 500 | TL750M05QKTTRQ1 | TL750M05Q1 |
| | 5 V | TO-252-3 – KVU | Reel of 2500 | TL750M05QKVURQ1 | 750M05Q |
| | 0 \/ | TO-263-3 – KTT | Reel of 500 | TL750M08QKTTRQ1 | TL750M08Q1 |
| | 8 V | TO-252-3 – KVU | Reel of 2500 | TL750M08QKVURQ1 | 750M08Q |
| | 12 V | TO-263-3 – KTT | Reel of 500 | TL750M12QKTTRQ1 | TL750M12Q1 |
| –40°C to 125°C | | TO-252-3 – KVU | Reel of 2500 | TL750M12QKVURQ1 | 750M12Q |
| -40 C to 125 C | 5 V | TO-263-5 – KTT | Reel of 500 | TL751M05QKTTRQ1 | TL751M05Q1 |
| | | TO-252-5 – KVU | Reel of 2500 | TL751M05QKVURQ1 | 751M05Q |
| | 0.1/ | TO-263-5 – KTT | Reel of 500 | TL751M08QKTTRQ1 | TL751M08Q1 |
| | 8 V | TO-252-5 – KVU | Reel of 2500 | TL751M08QKVURQ1 | 751M08Q |
| | 10.1/ | TO-263-5 – KTT | Reel of 500 | TL751M12QKTTRQ1 | TL751M12Q1 |
| | 12 V | TO-252-5 – KVU | Reel of 2500 | TL751M12QKVURQ1 | 751M12Q |

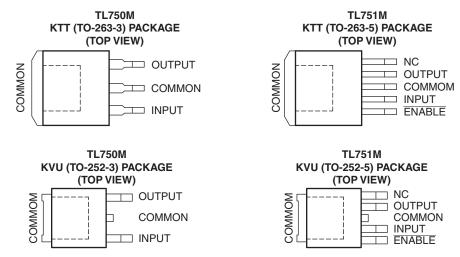
⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

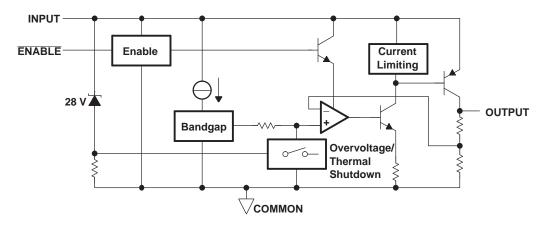
⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.





NOTE: The COMMON terminal is in electrical contact with the mounting base. NC – No internal connection

TL751Mxx FUNCTIONAL BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

| | Continuous input voltage | | 26 V |
|------------------|--|---------------------|----------------|
| | Transient input voltage (see Figure 4) | | 60 V |
| | Continuous reverse input voltage | | –15 V |
| | Transient reverse input voltage | t = 100 ms | –50 V |
| | | KTT package (3 pin) | 26.9°C/W |
| θ_{JA} | Package thermal impedance (2) (3) | KTT package (5 pin) | 26.5°C/W |
| | | KVU package | 38.6°C/W |
| T_{J} | Virtual junction temperature range | –40°C to 150°C | |
| T _{stg} | Storage temperature range | | −65°C to 150°C |

- (1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_J(max) T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can impact reliability. Due to variation in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.
- (3) The package thermal impedance is calculated in accordance with JESD 51.

THERMAL INFORMATION

| | | TL750M05 | |
|------------------|---|----------|----------|
| | THERMAL METRIC(1) | КТТ | UNITS |
| | | 3 PINS | |
| θ_{JA} | Junction-to-ambient thermal resistance ⁽²⁾ | 27.5 | |
| θ_{JCtop} | Junction-to-case (top) thermal resistance ⁽³⁾ | 43.2 | |
| θ_{JB} | Junction-to-board thermal resistance ⁽⁴⁾ | 17.3 | °C // // |
| Ψлт | Junction-to-top characterization parameter ⁽⁵⁾ | 2.8 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter ⁽⁶⁾ | 9.3 | |
| θ_{JCbot} | Junction-to-case (bottom) thermal resistance ⁽⁷⁾ | 0.3 | |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

RECOMMENDED OPERATING CONDITIONS

| | | | MIN | MAX | UNIT |
|----------|--|----------|-----|-----|------|
| | | TL75xM05 | 6 | 26 | |
| VI | Input voltage | TL75xM08 | 9 | 26 | V |
| | | TL75xM12 | 13 | 26 | |
| V_{IH} | High-level ENABLE input voltage | TL751Mxx | 2 | 15 | V |
| V_{IL} | Low-level ENABLE input voltage | TL751Mxx | 0 | 0.8 | V |
| Io | Output current | TL75xMxx | | 750 | mA |
| T_{J} | Operating virtual junction temperature | TL75xMxx | -40 | 125 | °C |



TL751Mxx ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}, I_O = 300 \text{ mA}, T_J = 25^{\circ}\text{C}$

| PARAMETER | TL751Mxx | UNIT |
|--|----------|------|
| PARAMETER | TYP | UNIT |
| Response time, ENABLE to output (start-up) | 50 | μs |

TL750M05/TL751M05 ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}$, $I_O = 300 \text{ mA}$, ENABLE at 0 V for TL751M05, $T_J = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

| PARAMETER | TEST CONDITIONS | TL750M05 TL751M05 | UNIT |
|----------------------------------|---|----------------------|---------|
| | | MIN TYP MA | X |
| Output voltage | V _I = 6 V to 26 V | 4.85 5 5. | 15 V |
| Line regulation | $V_I = 9 \text{ V to } 16 \text{ V}, \qquad I_O = 250 \text{ mA}$ | 10 | 25 |
| Line regulation | $V_I = 6 \text{ V to } 26 \text{ V}, \qquad I_O = 250 \text{ mA}$ | 12 | mV |
| Power-supply ripple rejection | $V_1 = 8 \text{ V to } 18 \text{ V}, \qquad f = 120 \text{ Hz}$ | 55 | dB |
| Load regulation | I _O = 5 mA to 750 mA | 20 | 50 mV |
| Dropout voltage (2) | $I_{O} = 500 \text{ mA}, T_{J} = 25^{\circ}\text{C}$ | (| .5 V |
| Dropout voltage — | $I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$ | 0. | |
| Current consumption | I _O = 750 mA | 60 | 75 |
| $I_{q} = I_{I} - I_{O}$ | I _O = 10 mA | | mA 5 |
| Shutdown current (TL751M05 only) | ENABLE V _{IH} ≥ 2 V | 2 | 00 μΑ |

¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4.

TL750M08/TL751M08 ELECTRICAL CHARACTERISTICS

 $V_I = 14 \text{ V}$, $I_O = 300 \text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M08, $T_J = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

| PARAMETER | TEST CONDITIONS | TL750M08 TL751M08 | UNIT | | | | |
|----------------------------------|--|----------------------|-------|----|--|--|--|
| | | MIN TYP | MAX | | | | |
| Output voltage | V _I = 6 V to 26 V | 7.76 8 | 8.24 | V | | | |
| I the area and artists | $V_I = 10 \text{ V to } 17 \text{ V}, \qquad I_O = 250 \text{ mA}$ | 12 | 40 | mV | | | |
| Line regulation | $V_1 = 9 \text{ V to } 26 \text{ V}, \qquad I_0 = 250 \text{ mA}$ | 15 | 15 68 | | | | |
| Power-supply ripple rejection | $V_1 = 11 \text{ V to } 21 \text{ V}, \qquad f = 120 \text{ Hz}$ | 55 | | dB | | | |
| Load regulation | I _O = 5 mA to 750 mA | 24 | 80 | mV | | | |
| Dropout voltage (2) | I _O = 500 mA, T _J = 25°C | | 0.5 | V | | | |
| Dropout voltage 7 | $I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$ | | 0.65 | V | | | |
| Current consumption | $I_{O} = 750 \text{ mA}, T_{J} = 25^{\circ}\text{C}$ | 60 | 75 | A | | | |
| $I_{q} = I_{I} - I_{O}$ | I _O = 10 mA | | 5 | mA | | | |
| Shutdown current (TL751M08 only) | ENABLE V _{IH} ≥ 2 V | | 200 | μΑ | | | |

⁽¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4.

⁽²⁾ Measured when the output voltage, V_0 , has dropped 100 mV from the nominal value obtained at $V_1 = 14$ V.

⁽²⁾ Measured when the output voltage, V_0 , has dropped 100 mV from the nominal value obtained at $V_1 = 14$ V.



TL750M12/TL751M12 ELECTRICAL CHARACTERISTICS

 $V_1 = 14 \text{ V}$, $I_0 = 300 \text{ mA}$, $\overline{\text{ENABLE}}$ at 0 V for TL751M12, $T_1 = -40^{\circ}\text{C}$ to 125°C (unless otherwise noted)⁽¹⁾

| PARAMETER | TEST CONDITIONS | 1 | TL750M12 TL751M12 | | | | |
|----------------------------------|--|-------|----------------------|-------|----|--|--|
| | | MIN | TYP | MAX | | | |
| Output voltage | V _I = 13 V to 26 V | 11.76 | 12 | 12.24 | V | | |
| lies as addiss | $V_I = 14 \text{ V to } 19 \text{ V}, \qquad I_O = 250 \text{ mA}$ | | 15 | 43 | | | |
| Line regulation | $V_{I} = 13 \text{ V to } 26 \text{ V}, \qquad I_{O} = 250 \text{ mA}$ | | 20 | 78 | mV | | |
| Power-supply ripple rejection | V _I = 13 V to 23 V, f = 120 Hz | 50 | 55 | | dB | | |
| Load regulation | $I_O = 5$ mA to 750 mA | | 30 | 120 | mV | | |
| Dropout voltage ⁽²⁾ | $I_{O} = 500 \text{ mA}, T_{J} = 25^{\circ}\text{C}$ | | | 0.5 | | | |
| Dropout voltage (=/ | $I_O = 750 \text{ mA}, T_J = 25^{\circ}\text{C}$ | | | 0.6 | V | | |
| Current consumption | $I_{O} = 750 \text{ mA}, T_{J} = 25^{\circ}\text{C}$ | | 60 | 75 | A | | |
| $I_q = I_l - I_O$ | I _O = 10 mA | | | 5 | mA | | |
| Shutdown current (TL751M12 only) | ENABLE V _{IH} ≥ 2 V | | | 200 | μA | | |

⁽¹⁾ Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-µF capacitor across the input and a 10-µF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 4. Measured when the output voltage, V_O , has dropped 100 mV from the nominal value obtained at V_I = 14 V.



PARAMETER MEASUREMENT INFORMATION

The TL750Mxx and TL751Mxx are low-dropout regulators. The output capacitor value and the parasitic equivalent series resistance (ESR) affect the bandwidth and stability of the control loop for these devices. For this reason, the capacitor and ESR must be carefully selected for a given operating temperature and load range. Figure 2 and Figure 3 can be used to establish the appropriate capacitance value and ESR for the best regulator transient response.

Figure 2 shows the recommended range of ESR for a given load with a 10- μ F capacitor on the output. Figure 2 also shows a maximum ESR limit of 2 Ω and a load-dependent minimum ESR limit.

For applications with varying loads, the lightest load condition should be chosen because it is the worst case. Figure 3 shows the relationship of the reciprocal of ESR to the square root of the capacitance, with a minimum capacitance limit of 10 μ F and a maximum ESR limit of 2 Ω . This figure establishes the amount that the minimum ESR limit shown in Figure 2 can be adjusted for different capacitor values. For example, where the minimum load needed is 200 mA, Figure 2 suggests an ESR range of 0.8 Ω to 2 Ω for 10 μ F. Figure 3 shows that changing the capacitor from 10 μ F to 400 μ F can change the ESR minimum by greater than 3/0.5 (or 6). Therefore, the new minimum ESR value is 0.8/6 (or 0.13 Ω). This allows an ESR range of 0.13 Ω to 2 Ω , achieving an expanded ESR range by using a larger capacitor at the output. For better stability in low-current applications, a small resistance placed in series with the capacitor (see Table 1) is recommended, so that ESRs better approximate those shown in Figure 2 and Figure 3.

Table 1. Compensation for Increased Stability at Low Currents

| MANUFACTURER | CAPACITANCE | ESR TYP | PART NUMBER | ADDITIONAL RESISTANCE |
|--------------|-------------|---------|----------------|-----------------------|
| AVX | 15 μF | 0.9 Ω | TAJB156M010S | 1 Ω |
| KEMET | 33 µF | 0.6 Ω | T491D336M010AS | 0.5 Ω |

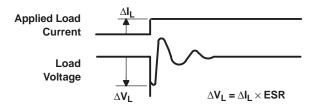


Figure 1.



OUTPUT CAPACITOR EQUIVALENT SERIES RESISTANCE (ESR) vs LOAD CURRENT RANGE

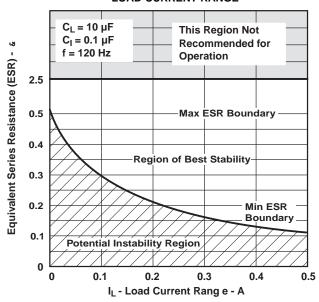


Figure 2.

STABILITY vs EQUIVALENT SERIES RESISTANCE (ESR)

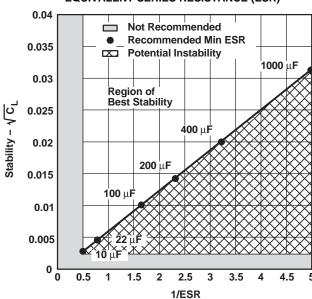


Figure 3.

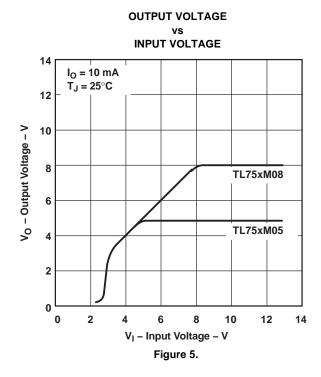


TYPICAL CHARACTERISTICS

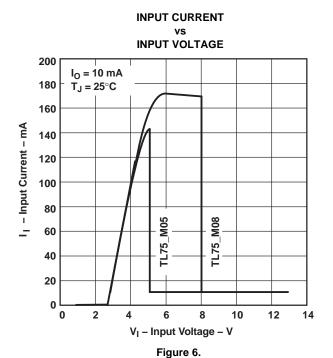
Table 2. Table of Graphs

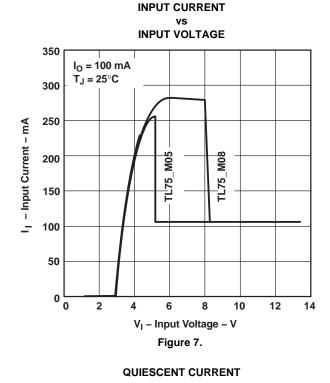
| | | | FIGURE |
|-------------------------|-------------------|-------------------------|--------|
| Transient input voltage | vs Time | | 4 |
| Output voltage | vs Input voltage | | 5 |
| Lawret access of | vo lanut voltage | I _O = 10 mA | 6 |
| Input current | vs Input voltage | I _O = 100 mA | 7 |
| Dropout voltage | vs Output current | | 8 |
| Quiescent current | vs Output current | | 9 |
| Load transient response | 10 | | |
| Line transient response | 11 | | |

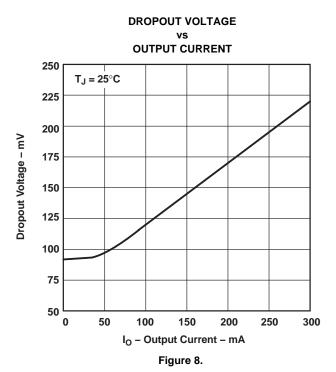
TRANSIENT INPUT VOLTAGE TIME 60 $T_J = 25^{\circ}C$ V_{I} = 14 V + 46e^(-t/0.230) for t \geq 5 ms 50 V_I - Transient Input Voltage - V 40 30 t_r = 1 ms 20 10 0 100 200 300 400 500 600 t - Time - ms Figure 4.

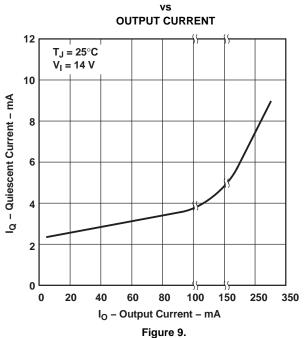




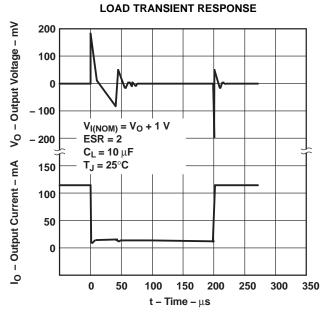














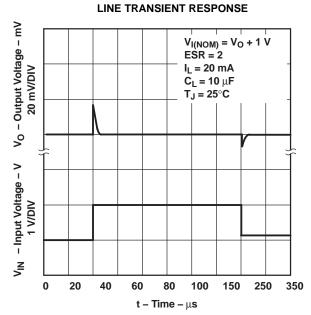


Figure 11.





10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|------------------|--------------------|------|----------------|--------------|-------------------------------|---------------------|--------------|----------------------|---------|
| TL750M05QKTTRQ1 | ACTIVE | DDPAK/ TO-263 | KTT | 3 | 500 | RoHS & Green | | Level-3-245C-168 HR | -40 to 125 | TL750M05Q1 | Samples |
| TL750M05QKVURQ1 | ACTIVE | TO-252 | KVU | 3 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 750M05Q | Samples |
| TL750M08QKVURQ1 | ACTIVE | TO-252 | KVU | 3 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 750M08Q | Samples |
| TL750M12QKTTRQ1 | ACTIVE | DDPAK/ TO-263 | KTT | 3 | 500 | RoHS & Green | SN | Level-3-245C-168 HR | -40 to 125 | TL750M12Q1 | Samples |
| TL750M12QKVURQ1 | ACTIVE | TO-252 | KVU | 3 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 750M12Q | Samples |
| TL751M05QKVURQ1 | ACTIVE | TO-252 | KVU | 5 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 751M05Q | Samples |
| TL751M08QKTTRQ1 | ACTIVE | DDPAK/ TO-263 | KTT | 5 | 500 | RoHS & Green | SN | Level-3-245C-168 HR | -40 to 125 | TL751M08Q1 | Samples |
| TL751M08QKVURQ1 | ACTIVE | TO-252 | KVU | 5 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 751M08Q | Samples |
| TL751M12QKTTRQ1 | ACTIVE | DDPAK/ TO-263 | KTT | 5 | 500 | RoHS & Green | SN | Level-3-245C-168 HR | -40 to 125 | TL751M12Q1 | Samples |
| TL751M12QKVURQ1 | ACTIVE | TO-252 | KVU | 5 | 2500 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | 751M12Q | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

10-Dec-2020

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TL750M-Q1:

Catalog: TL750M

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Apr-2020

TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO P1 BO W Cavity AO

| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| ^All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|------------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| TL750M05QKVURQ1 | TO-252 | KVU | 3 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |
| TL750M08QKVURQ1 | TO-252 | KVU | 3 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |
| TL750M12QKTTRQ1 | DDPAK/ TO-263 | KTT | 3 | 500 | 330.0 | 24.4 | 10.6 | 15.8 | 4.9 | 16.0 | 24.0 | Q2 |
| TL750M12QKVURQ1 | TO-252 | KVU | 3 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |
| TL751M05QKVURQ1 | TO-252 | KVU | 5 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |
| TL751M08QKTTRQ1 | DDPAK/ TO-263 | KTT | 5 | 500 | 330.0 | 24.4 | 10.6 | 15.8 | 4.9 | 16.0 | 24.0 | Q2 |
| TL751M08QKVURQ1 | TO-252 | KVU | 5 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |
| TL751M12QKTTRQ1 | DDPAK/ TO-263 | KTT | 5 | 500 | 330.0 | 24.4 | 10.6 | 15.8 | 4.9 | 16.0 | 24.0 | Q2 |
| TL751M12QKVURQ1 | TO-252 | KVU | 5 | 2500 | 330.0 | 16.4 | 6.9 | 10.5 | 2.7 | 8.0 | 16.0 | Q2 |

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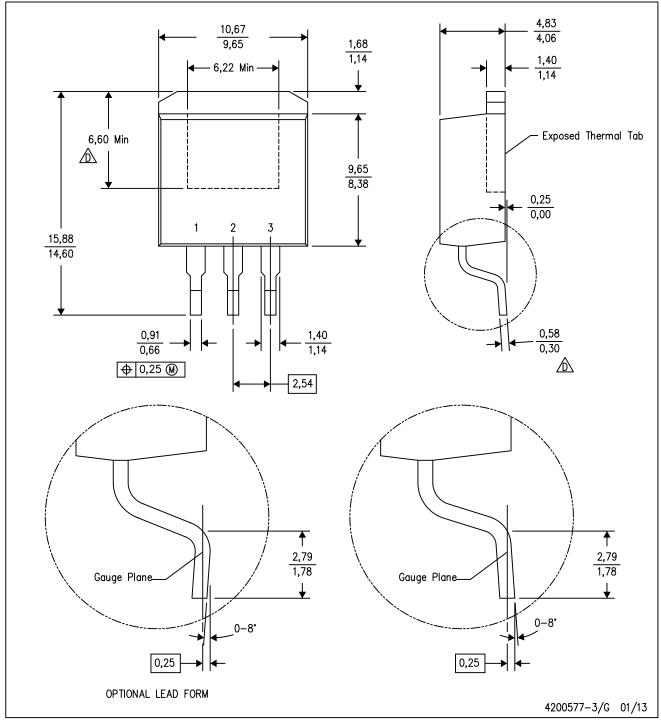


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TL750M05QKVURQ1 | TO-252 | KVU | 3 | 2500 | 340.0 | 340.0 | 38.0 |
| TL750M08QKVURQ1 | TO-252 | KVU | 3 | 2500 | 340.0 | 340.0 | 38.0 |
| TL750M12QKTTRQ1 | DDPAK/TO-263 | KTT | 3 | 500 | 340.0 | 340.0 | 38.0 |
| TL750M12QKVURQ1 | TO-252 | KVU | 3 | 2500 | 340.0 | 340.0 | 38.0 |
| TL751M05QKVURQ1 | TO-252 | KVU | 5 | 2500 | 340.0 | 340.0 | 38.0 |
| TL751M08QKTTRQ1 | DDPAK/TO-263 | KTT | 5 | 500 | 340.0 | 340.0 | 38.0 |
| TL751M08QKVURQ1 | TO-252 | KVU | 5 | 2500 | 340.0 | 340.0 | 38.0 |
| TL751M12QKTTRQ1 | DDPAK/TO-263 | KTT | 5 | 500 | 340.0 | 340.0 | 38.0 |
| TL751M12QKVURQ1 | TO-252 | KVU | 5 | 2500 | 340.0 | 340.0 | 38.0 |

KTT (R-PSFM-G3)

PLASTIC FLANGE-MOUNT PACKAGE

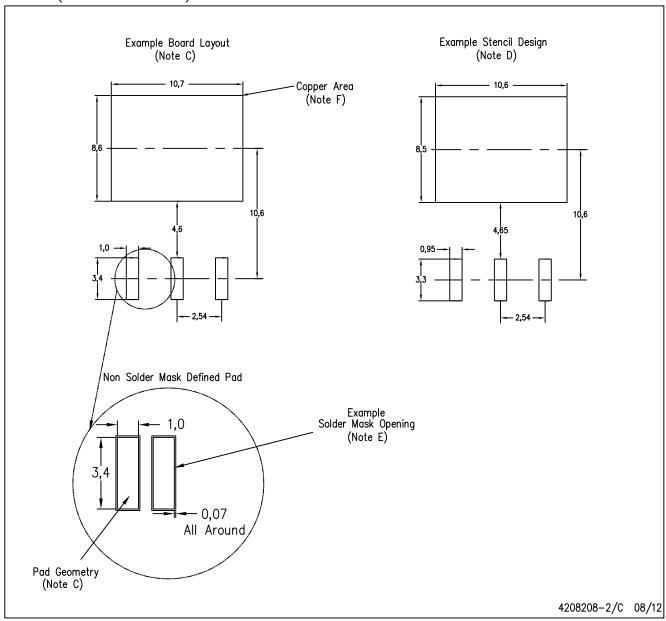


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- ⚠ Falls within JEDEC T0—263 variation AA, except minimum lead thickness and minimum exposed pad length.



KTT (R-PSFM-G3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A.

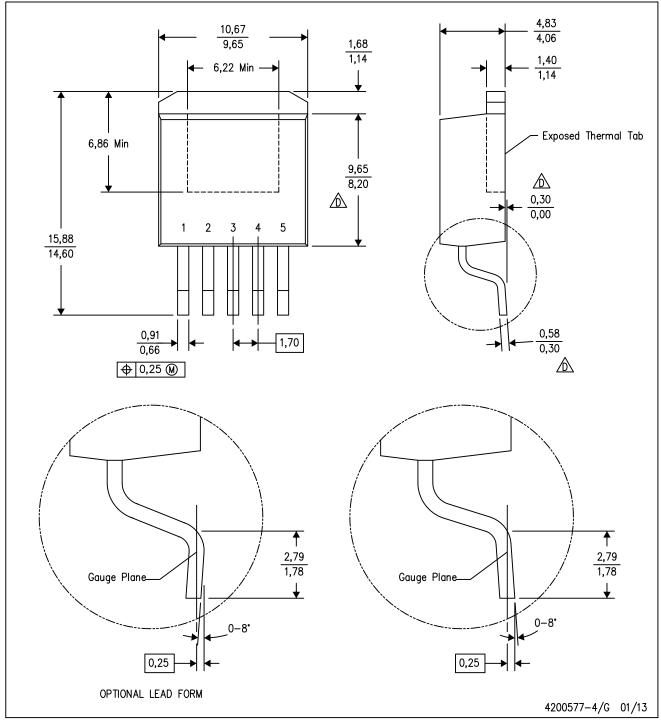
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

 Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.



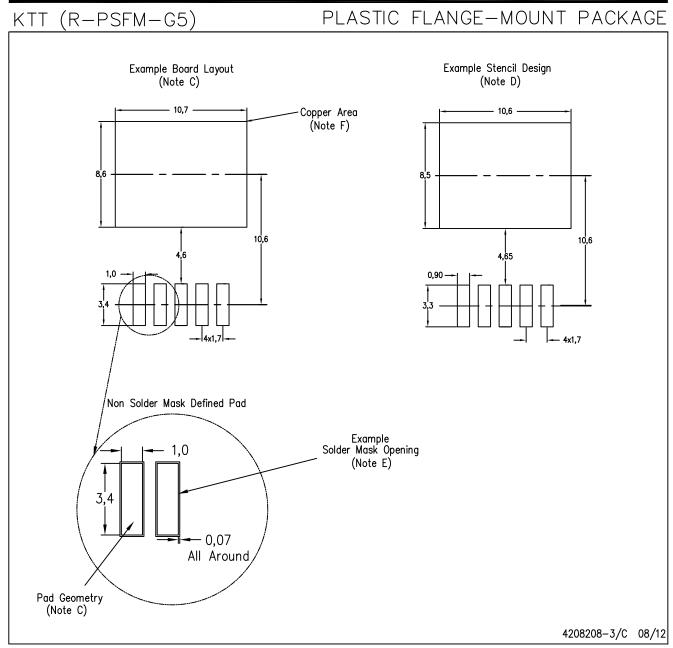
KTT (R-PSFM-G5)

PLASTIC FLANGE-MOUNT PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- Falls within JEDEC T0—263 variation BA, except minimum lead thickness, maximum seating height, and minimum body length.



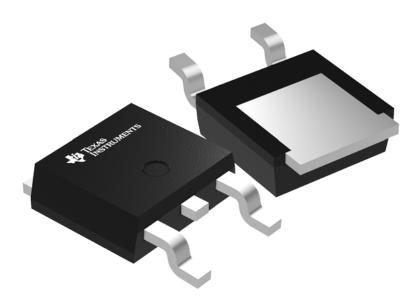


NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

 Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.





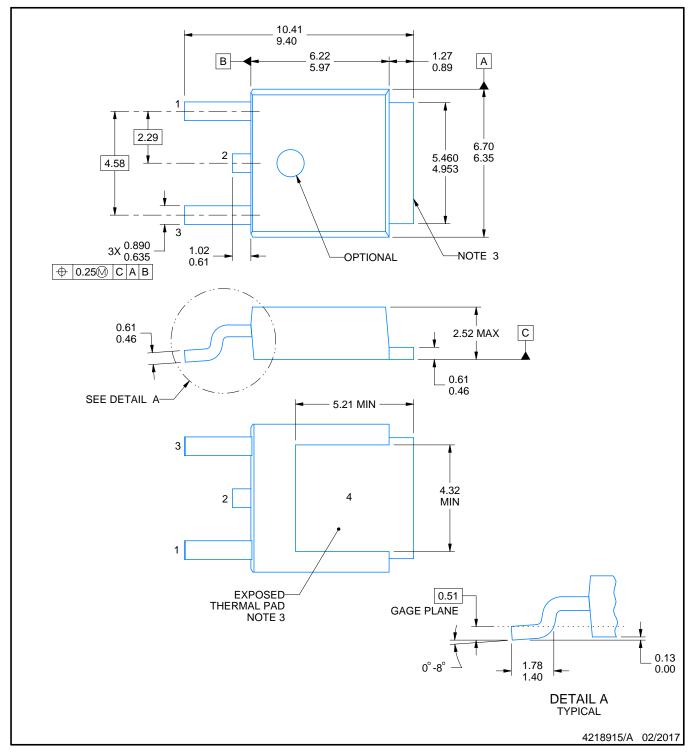
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4205521-2/E





TO-252



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

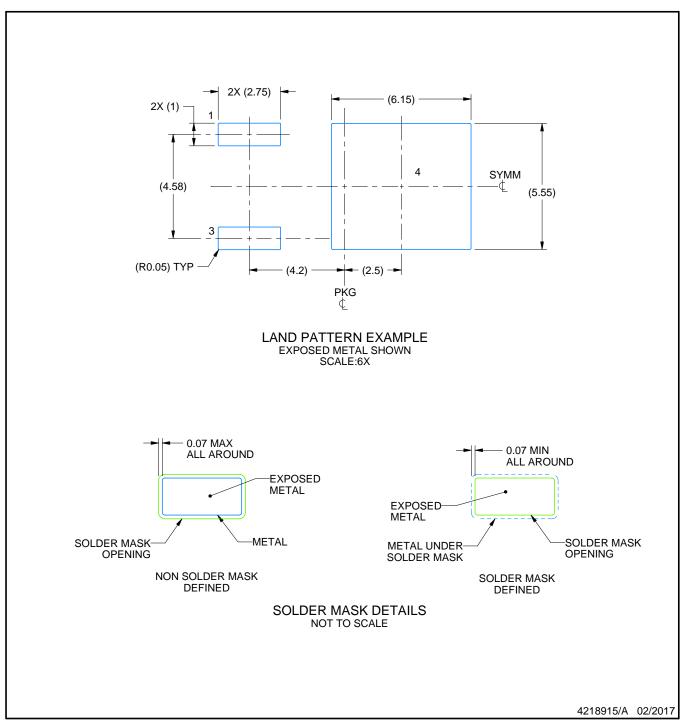
 2. This drawing is subject to change without notice.

 3. Shape may vary per different assembly sites.

 4. Reference JEDEC registration TO-252.



TO-252

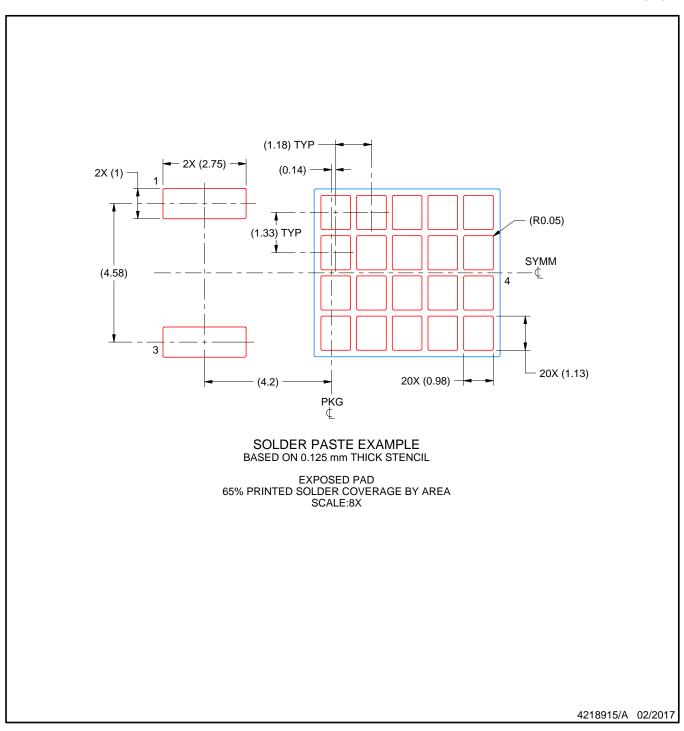


NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
- 6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



TO-252



NOTES: (continued)

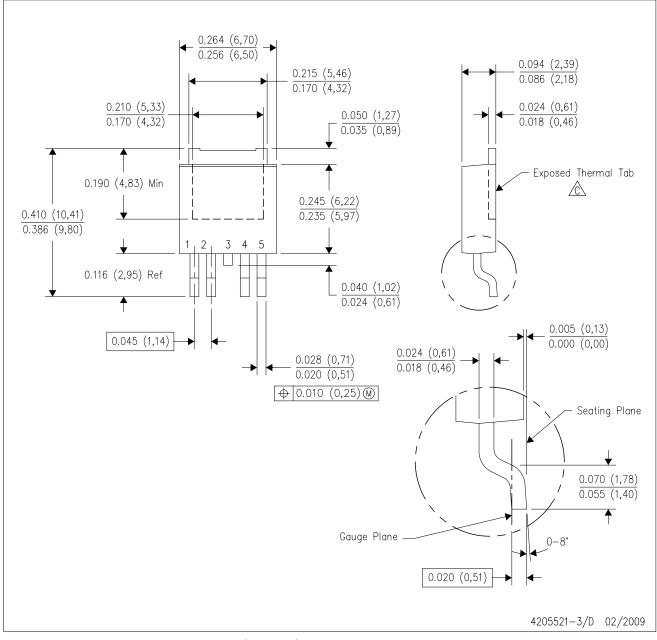


^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.

KVU (R-PSFM-G5)

PLASTIC FLANGE-MOUNT PACKAGE

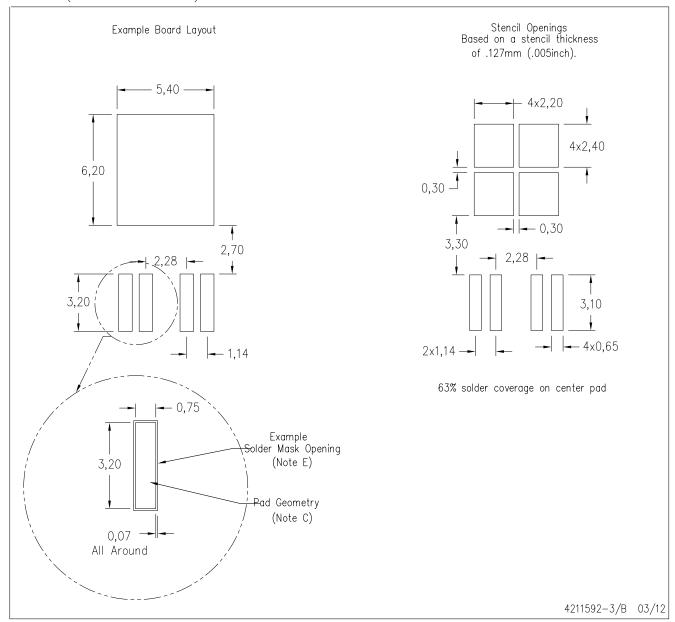


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- The center lead is in electrical contact with the exposed thermal tab.
- D. Body Dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.006 (0,15) per side.
- E. Falls within JEDEC TO-252 variation AD.



KVU (R-PSFM-G5)

PLASTIC FLANGE MOUNT PACKAGE



- A. All linear dimensions are in millimeters.
- 3. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is an alternate information source for PCB land pattern designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in thermal pad.



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